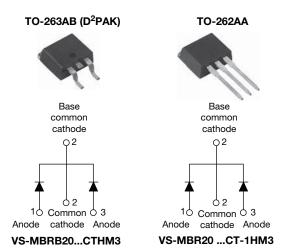


# VS-MBRB20...CTHM3, VS-MBR20...CT-1HM3

Vishay Semiconductors

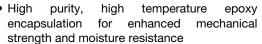
# High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMM	PRODUCT SUMMARY						
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA						
I <sub>F(AV)</sub>	2 x 10 A						
$V_{R}$	80 V, 100 V						
V <sub>F</sub> at I <sub>F</sub>	0.70 V						
I <sub>RM</sub>	6 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Common cathode						
E <sub>AS</sub>	24 mJ						

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation
- Center tap D<sup>2</sup>PAK and TO-262 packages





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	^				
I <sub>FRM</sub>	T <sub>C</sub> = 133 °C (per leg)	20	A				
V <sub>RRM</sub>		80 to 100	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	Α				
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.70	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB2080CTHM3 VS-MBR2080CT-1HM3	VS-MBRB2090CTHM3 VS-MBR2090CT-1HM3	VS-MBRB20100CTHM3 VS-MBR20100CT-1HM3	UNITS
Maximum DC reverse voltage	$V_{R}$	80	90	100	V
Maximum working peak reverse voltage	$V_{RWM}$	60	90	100	V



# VS-MBRB20...CTHM3, VS-MBR20...CT-1HM3

# Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	Т	TEST CONDITIONS		UNITS		
Maximum average per leg	1	T 122 °C rated	V-	10			
forward current per device	I <sub>F(AV)</sub>	$T_C = 133 ^{\circ}\text{C}, \text{ rated V}_R$		20			
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 133 °C		20			
Non repetitive peak aurae aurant		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	850	Α		
Non-repetitive peak surge current	IFSM	Surge applied at rated load conditions half wave, single phase, 60 Hz		150			
Peak repetitive reverse surge current	I <sub>RRM</sub>	2.0 μs, 1.0 kHz		0.5			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_{J} = 25  ^{\circ}\text{C},  I_{AS} = 2$	A, L = 12 mH	24	mJ		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUES	UNITS	
		10 A	T <sub>.1</sub> = 25 °C	0.80	V	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	20 A	11 = 23 0	0.95		
	VFM (*/	10 A	T <sub>.1</sub> = 125 °C	0.70		
		20 A	1j = 125 C	0.85		
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Dated DC valtage	0.10	- mA	
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	Rated DC voltage	6		
Threshold voltage	V <sub>F(TO)</sub>	T - T mavimum		0.433	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		15.8	$m\Omega$	
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	nge 100 kHz to 1 MHz), 25 °C	400	pF	
Typical series inductance	L <sub>S</sub>	Measured from top of terr	minal to mounting plane	8.0	nΗ	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range		TJ		-55 to +150	°C			
Maximum storage temper	ature range	T <sub>Stg</sub>		-65 to +150				
Maximum thermal resistar junction to case per leg	nce,	R <sub>thJC</sub>	DC operation	2.0				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W			
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DC operation	50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)			
Mounting torque	maximum		Non-iubricated tilleads	12 (10)				
				MBRB20	090CTH			
Marking device			Case style D <sup>2</sup> PAK	MBRB20	080CTH			
					100CTH			
				MBR209	0CT-1H			
			Case style TO-262	MBR208	OCT-1H			
				MBR2010	00CT-1H			



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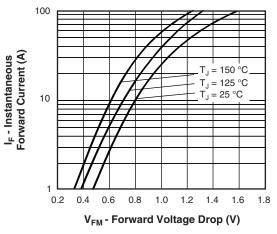


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

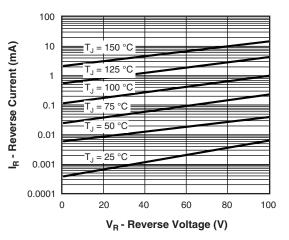


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

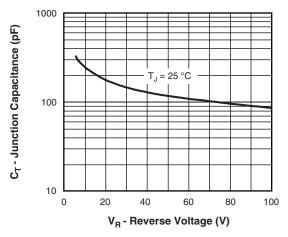


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

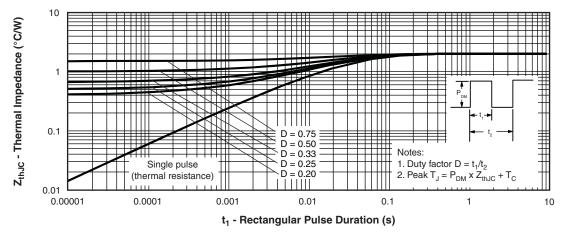


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

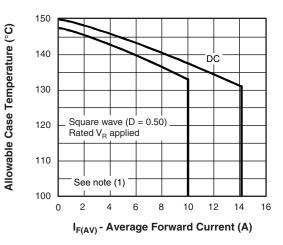


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

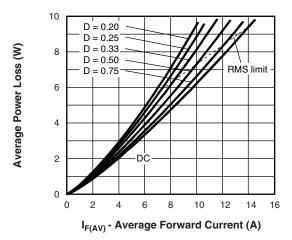


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

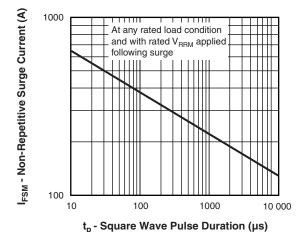


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

### Note

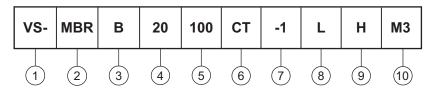
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

# VS-MBRB20...CTHM3, VS-MBR20...CT-1HM3

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

Essential part number

•  $B = D^2PAK$ | 7 | None

• None = TO-262 7 = -1

Current rating (20 = 20 A)

80 = 80 V90 = 90 VVoltage ratings -100 = 100 V

CT = common cathode

5

• None =  $D^2PAK$  3 = B

• -1 = TO-262 3 None

8 | • None = tube (50 pieces)

• L = tape and reel (left oriented - for D<sup>2</sup>PAK only)

• R = tape and reel (right oriented - for D<sup>2</sup>PAK only)

• H = AEC-Q101 qualified

10 • M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMAT	ION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBRB2080CTHM3	50	1000	Antistatic plastic tube
VS-MBRB2090CTHM3	50	1000	Antistatic plastic tube
VS-MBRB20100CTHM3	50	1000	Antistatic plastic tube
VS-MBRB2080CTLHM3	800	800	13" diameter reel
VS-MBRB2090CTLHM3	800	800	13" diameter reel
VS-MBRB20100CTLHM3	800	800	13" diameter reel
VS-MBRB2080CTRHM3	800	800	13" diameter reel
VS-MBRB2090CTRHM3	800	800	13" diameter reel
VS-MBRB20100CTRHM3	800	800	13" diameter reel
VS-MBRB2080CT-1HM3	50	1000	Antistatic plastic tube
VS-MBRB2090CT-1HM3	50	1000	Antistatic plastic tube
VS-MBRB20100CT-1HM3	50	1000	Antistatic plastic tube

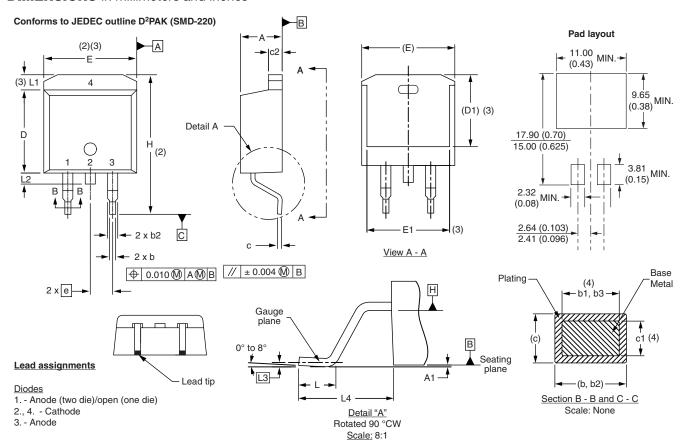
LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046				
Differsions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95032				



# Vishay Semiconductors

# D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

- $^{(1)}$  Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

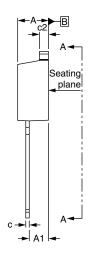


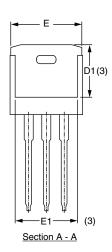
# Vishay Semiconductors

## **TO-262**

### **DIMENSIONS** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) L1 D D D C C C C A (2) A (2) A (3) L2 B B B B C C C A (2)



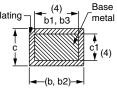


**⊕** 0.010**⋒**|A**⋒**|B

### Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CVMPOL	MILLIN	METERS	INCH	IES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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Revision: 02-Oct-12 Document Number: 91000

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